# **Electronic Structure Analysis on Fluorine Induced LaNiO3 Perovskite Oxides**

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Perovskite-type oxides, LaNiO<sub>3</sub>, have been used as electrocatalysts for the oxygen evolution reaction (OER) in alkaline water electrolyzers. For further development of high OER activity, the tailoring of defect chemistry is important. This study attempts to introduce fluoride ions into the crystal structure of LaNiO<sub>3</sub> by chemical fluorination. Mixtures of LaNiO<sub>3</sub> and polyvinylidene difluoride (PVDF) are annealed at 350 °C. The products are characterized by X-ray diffraction and Ni, F and O *K*-edge X-ray absorption spectroscopy. Decomposition of PVDF results in fluorination of LaNiO<sub>3</sub> with decreasing Ni valence state. The highly ionic nature of the fluoride ion reduces the hybridization state between O 2p and Ni 3d orbitals.

## 1. Introduction

Perovskite-type oxides have been used as electrocatalysts for oxygen evolution reaction (OER) in alkaline water electrolyzers. In the research of highly active perovskite-type oxides, the descriptor for OER has been studied. In simple perovskite oxides composed of lanthanides and 3d transition metals, the electrons in the eg orbitals in the transition metals affect the 2p orbitals formed by oxygen-derived intermediates under OER [1]. Therefore, the number of electrons in the eg orbitals can be used as a descriptor for OER, and it has been found that the activity is maximum when the number of eg electrons is 1.2 [1]. It has been reported that LaNiO<sub>3</sub> has an eg electron number of 1.0 and exhibits relatively high OER activity. Under conditions of reducing high temperature atmosphere, approximately 1% of oxygen deficiency is introduced into the LaNiO<sub>3</sub> crystal structure [2]. However, under strong reducing conditions, the perovskite-type structure is not stable [3], which makes it difficult to control the number of eg electrons. In this study, we have attempted to suppress the structural instability caused by oxygen vacancies by partially substituting fluorine for oxygen sites in LaNiO<sub>3</sub>. The chemical fluorination reactions of Sr<sub>3</sub>Fe<sub>2</sub>O<sub>6.28</sub> [4], BaFeO<sub>2.5</sub> [5], and  $La_2CuO_4$ [6], by using PTFE (polytetrafluoroethylene), PVDF (polyvinylidene difluoride), and NH4F, respectively, have been reported. Here, we investigate the topotactic fluorination reaction in LaNiO3 by annealing a mixture between LaNiO3 and PVDF in a sealed stainless-steel tube, where the reaction gas is released by thermal decomposition of PVDF. The

synthesized materials are characterized for crystal structure by X-ray diffraction (XRD), and then electronic structure analysis by Ni, F and O *K*-edges X-ray absorption spectroscopy (XAS) is performed.

#### 2. Experimental

LaNiO<sub>3</sub> (Kojundo Chemical Laboratory Co., Ltd.) and PVDF powder (Sigma-Aldrich) were each weighed and mixed in a mortar. The weight ratio of LaNiO<sub>3</sub> to PVDF was LaNiO<sub>3</sub>:PVDF=1:0.1 (hereafter denoted PVDF 10%) and 1:0.2 (PVDF 20%). The mixed samples were pelletized and sealed in a stainless-steel container. The sealed containers were annealed at 350°C for 12 hours. XRD experiment was performed using an Ultima-IV diffractometer (Rigaku) with Cu Ka radiation as the X-ray source and a tube voltage and current of 40 kV and 40 mA, respectively. Ni K-edge XAS measurements were performed at the beamline BL-4 in the Ritsumeikan University SR Center. The samples were mixed with BN and measured in transmission mode. F and O K-edge XAS measurements were carried out at the beamline BL-11 in the Ritsumeikan University SR Center. The powder samples were mounted on carbon tape, and the spectra were taken with the partial electron yield (PEY) and partial fluorescence yield (PFY) modes under vacuum.

### 3. Results and discussion

XRD patterns of LaNiO<sub>3</sub>, PVDF 10% and PVDF 20% are shown in Fig. 1. The PVDF-treated samples show a lower angle shift of the diffraction peaks, especially at higher angles, compared to LaNiO<sub>3</sub>. In addition, the peaks are broadened, indicating less



Fig. 1 XRD patterns of LaNiO<sub>3</sub> and annealed mixtures of LaNiO<sub>3</sub> containing PVDF 10% and 20%.



Fig. 2 Ni K-edge XANES of LaNiO<sub>3</sub> and PVDF 10%.

crystallinity in the PVDF-treated samples. Although most of the peaks are assigned to the reported LaNiO<sub>3</sub> phase with space group R3/C [7], unidentified peaks are observed for PVDF 20%, particularly around 25 degrees. This peak and the broadening around 32 degrees may be due to the formation of a LaNiO<sub>2.5</sub> defect perovskite phase [8], although sufficient crystal structure analysis has not been performed. The lattice parameter of PVDF 10% and PVDF 20% is larger than that of LaNiO<sub>3</sub>. The lattice expansion is due to the formation of Ni<sup>2+</sup> with large ionic radius than Ni<sup>3+</sup> by the nickel reduction reaction. The nickel reduction reaction is probably due to the introduction of oxygen defects and the progressive exchange reaction between oxide and fluoride ions. Therefore, the defect structure is discussed in terms of the electronic structure change from the results of XAS. In the following discussion, we will compare LaNiO3 and PVDF 10% to avoid ambiguity due to the impurity formation in PVDF 20%.

Figure 2 shows X-ray absorption near edge



Fig. 3 F *K*-edge XANES of LaNiO<sub>3</sub> and PVDF 10% obtained in PFY mode.

structures (XANES) at Ni K-edge of LaNiO3 and PVDF 10%, where the absorption edge appears at about 8340 eV. The Ni K-edge absorption is usually interpreted from the transition of core electrons to the Ni 4p empty states. Compared to LaNiO<sub>3</sub>, the spectrum of PVDF 10% is shifted towards lower energy. This is a direct result of the Ni reduction and is in good agreement with the crystal lattice expansion shown by XRD. Taking the position of the Ni K-edge from the energy at the half-maximum of the absorption, the observed energy shift is about 0.9 eV. This shift is consistent with the reported absorption edge difference between La<sub>2</sub>NiO<sub>4+ $\delta$ </sub> and  $La_4Ni_3O_{10-\delta}$ , where the valence shift was estimated to be 0.34 [9]. The synthesized PVDF 10% in this study is expected to have a similar nickel valence reduction compared to LaNiO<sub>3</sub>.

Figure 3 shows F *K*-edge XANES spectra of LaNiO<sub>3</sub> and PVDF 10% obtained in fluorescence mode without normalization. The absorption intensity at F *K*-edge of PVDF 10% is clearly observed. The XRD results have shown no clear phase-separation behavior in PVDF 10%, but F *K*-edge XANES spectra indicated that the heat treatment with PVDF introduces fluoride ions into the LaNiO<sub>3</sub> crystal structure without secondary phase formation. In this fluorination reaction, the Ni valence decreases at the same time. The reaction scheme of LaNiO<sub>3</sub> with PVDF treatment is shown below:

LaNiO<sub>3</sub> + 0.5x F<sub>2</sub>  $\rightarrow$  LaNiO<sub>3-x</sub>F<sub>x</sub> + 0.5x O<sub>2</sub> (1). It is shown that fluoride ions are incorporated into the oxygen defect sites, resulting in a decrease in the Ni valence.

The substitution of oxide ions by fluoride ions may cause the electronic structure change in the oxygen orbital. Figures 4 (a) and (b) show the O *K*edge XANES of LaNiO<sub>3</sub> and PVDF 10% obtained in PEY and PFY modes, respectively. The spectra



Fig. 4 O *K*-edge XANES of LaNiO<sub>3</sub> and PVDF 10% obtained in (a) PEY and (b) PFY modes.

correspond to the electron transition from the O 1s core level to the unoccupied states. The first peak at 528 eV is attributed to the hybridization state, which is related to the character of the O 2p-Ni 3d states [10]. The second peaks at 532 eV correspond to the band of La 5d characters. The broad peak centered at 540 eV is due to the Ni 4sp character. The first peak at 528 eV disappears for PVDF 10% especially in the XANES measured in PEY mode. This indicates that the hybridization between O 2p and Ni 3d is weakened by the introduction of fluoride ions into the oxide ion site on the surface of LaNiO3 due to the highly ionic nature of fluoride ions in LaNiO<sub>3</sub>. The decrease of hybridization state was reported in the introduction of oxygen deficiency in La<sub>0.6</sub>Sr<sub>0.4</sub>CoO<sub>3-δ</sub> [11]. The observed electronic structure change in fluorine induced LaNiO<sub>3</sub> might influence OER activity.

## 4. Conclusions

This study has examined the fluorination reaction to LaNiO<sub>3</sub> by annealing of a mixture of LaNiO<sub>3</sub> and PVDF. Calcination of the PVDF mixture introduces fluoride ions into LaNiO<sub>3</sub>, but the high ratio of PDVF causes phase separation. Ni *K*-edge XANES analysis has revealed the decreasing of Ni valence by the calcination of PVDF mixture. The observed Ni reduction is due to oxygen defect formation and/or fluoride ion substitution on oxide ion site. O *K*-edge XANES shows that the introduction of highly ionic fluoride ions weakens the hybridization between O 2p and Ni 3*d* states.

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